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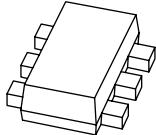
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Kind regards,

Team Nexperia



PBSS5160V

60 V, 1 A PNP low V_{CEsat} (BISS) transistor

Rev. 03 — 14 December 2009

Product data sheet

1. Product profile

1.1 General description

PNP low V_{CEsat} Breakthrough in Small Signals (BISS) transistor in a SOT666 plastic package.

NPN complement: PBSS4160V.

1.2 Features

- Low collector-emitter saturation voltage V_{CEsat}
- High collector current capability I_C and I_{CM}
- High efficiency leading to less heat generation
- Reduces printed-circuit board area required
- Cost effective replacement for medium power transistors BCP52 and BCX52

1.3 Applications

- Major application segments
 - ◆ Automotive
 - ◆ Telecom infrastructure
 - ◆ Industrial
- Power management
 - ◆ DC-to-DC conversion
 - ◆ Supply line switching
- Peripheral driver
 - ◆ Driver in low supply voltage applications (e.g. lamps and LEDs)
 - ◆ Inductive load driver (e.g. relays, buzzers and motors)

1.4 Quick reference data

Table 1. Quick reference data

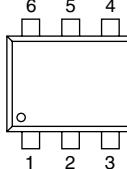
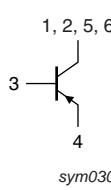
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	-60	V
I_C	collector current (DC)		[1]	-	-1	A
I_{CM}	peak collector current		-	-	-2	A
R_{CEsat}	equivalent on-resistance	$I_C = -1\text{ A};$ $I_B = -100\text{ mA}$	-	220	330	$\text{m}\Omega$

[1] Device mounted on a FR4 PCB, single-sided copper, tin-plated and standard footprint.

2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Symbol
1, 2, 5, 6	collector		
3	base		
4	emitter		

sym030

3. Ordering information

Table 3. Ordering information

Type number	Package		Version
	Name	Description	
PBSS5160V	-	plastic surface mounted package; 6 leads	SOT666

4. Marking

Table 4. Marking codes

Type number	Marking code
PBSS5160V	51

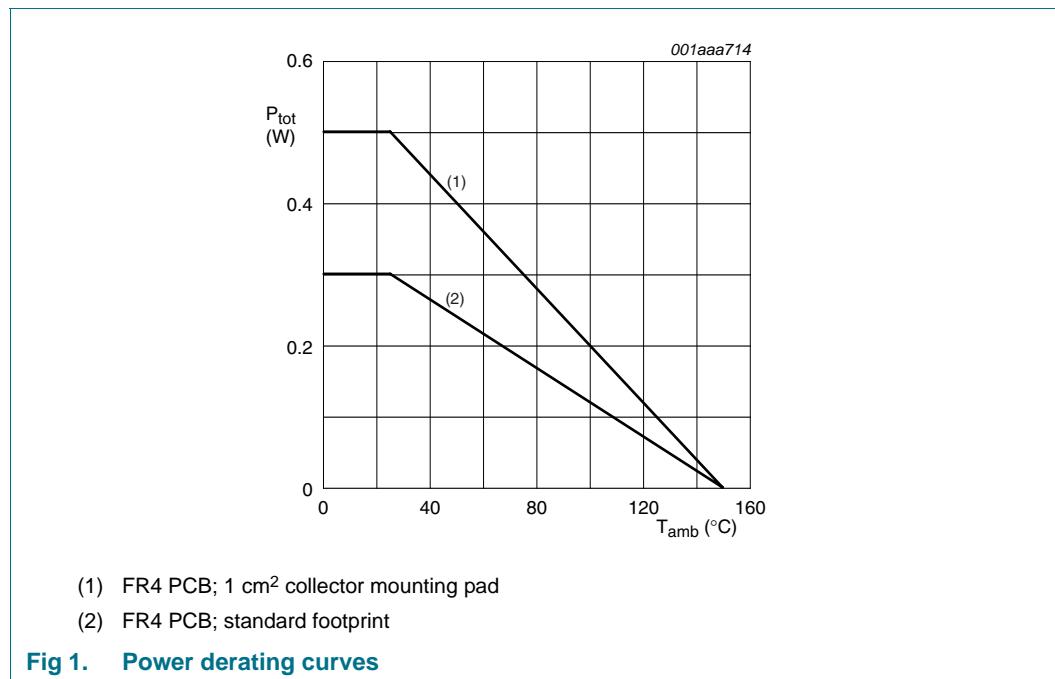
5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter	-	-80	V
V_{CEO}	collector-emitter voltage	open base	-	-60	V
V_{EBO}	emitter-base voltage	open collector	-	-5	V
I_C	collector current (DC)		[1]	-0.9	A
			[2]	-1	A
I_{CM}	peak collector current	$t = 1 \text{ ms}$ or limited by $T_{j(\max)}$	-	-2	A
I_B	base current (DC)		-	-300	mA
I_{BM}	peak base current	$t_p \leq 300 \mu\text{s}; \delta \leq 0.02$	-	-1	A
P_{tot}	total power dissipation	$T_{amb} \leq 25^\circ\text{C}$	[1]	300	mW
			[2]	500	mW
T_j	junction temperature		-	150	°C
T_{amb}	ambient temperature		-65	+150	°C
T_{stg}	storage temperature		-65	+150	°C

- [1] Device mounted on a FR4 PCB, single-sided copper, tin-plated and standard footprint.
 [2] Device mounted on a FR4 PCB, single-sided copper, tin-plated, 1 cm² collector mounting pad.

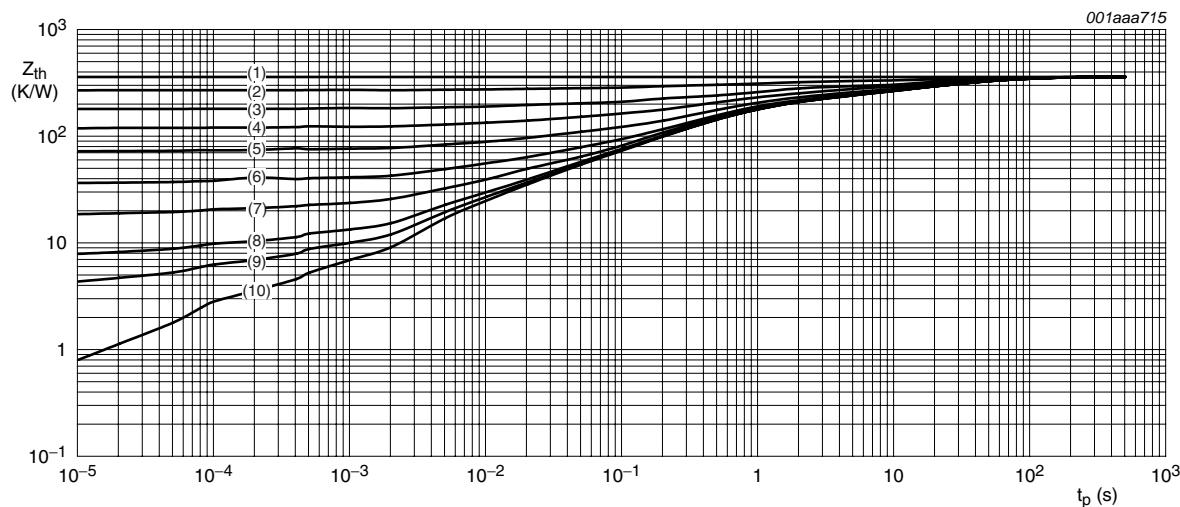


6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1] -	-	415	K/W

- [1] Device mounted on a FR4 PCB, single-sided copper, tin-plated and standard footprint.
 [2] Device mounted on a FR4 PCB, single-sided copper, tin-plated, 1 cm² collector mounting pad.



Mounted on FR4 PCB; standard footprint

- (1) $\delta = 1$
- (2) $\delta = 0.75$
- (3) $\delta = 0.5$
- (4) $\delta = 0.33$
- (5) $\delta = 0.2$
- (6) $\delta = 0.1$
- (7) $\delta = 0.05$
- (8) $\delta = 0.02$
- (9) $\delta = 0.01$
- (10) $\delta = 0$

Fig 2. Transient thermal impedance as a function of pulse time; typical values

7. Characteristics

Table 7. Characteristics $T_{amb} = 25^\circ\text{C}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
I_{CBO}	collector-base cut-off current	$V_{CB} = -60\text{ V}; I_E = 0\text{ A}$	-	-	-100	nA
		$V_{CB} = -60\text{ V}; I_E = 0\text{ A}; T_j = 150^\circ\text{C}$	-	-	-50	μA
I_{CES}	collector-emitter cut-off current	$V_{CE} = -60\text{ V}; V_{BE} = 0\text{ V}$	-	-	-100	nA
I_{EBO}	emitter-base cut-off current	$V_{EB} = -5\text{ V}; I_C = 0\text{ A}$	-	-	-100	nA
h_{FE}	DC current gain	$V_{CE} = -5\text{ V}; I_C = -1\text{ mA}$	200	350	-	
		$V_{CE} = -5\text{ V}; I_C = -500\text{ mA}$	[1]	150	250	-
		$V_{CE} = -5\text{ V}; I_C = -1\text{ A}$	[1]	100	160	-
V_{CEsat}	collector-emitter saturation voltage	$I_C = -100\text{ mA}; I_B = -1\text{ mA}$	-	-110	-160	mV
		$I_C = -500\text{ mA}; I_B = -50\text{ mA}$	-	-120	-175	mV
		$I_C = -1\text{ A}; I_B = -100\text{ mA}$	[1]	-	-220	-330
V_{BEsat}	base-emitter saturation voltage	$I_C = -1\text{ A}; I_B = -50\text{ mA}$	-	-0.95	-1.1	V
R_{CEsat}	equivalent on-resistance	$I_C = -1\text{ A}; I_B = -100\text{ mA}$	[1]	220	330	$\text{m}\Omega$
V_{BEon}	base-emitter turn-on voltage	$I_C = -1\text{ A}; V_{CE} = -5\text{ V}$	-	-0.82	-0.9	V
t_d	delay time	$V_{CC} = -10\text{ V}; I_C = -0.5\text{ A};$	-	11	-	ns
t_r	rise time	$I_{Bon} = -0.025\text{ A}; I_{Boff} = 0.025\text{ A}$	-	30	-	ns
t_{on}	turn-on time		-	41	-	ns
t_s	storage time		-	205	-	ns
t_f	fall time		-	55	-	ns
t_{off}	turn-off time		-	260	-	ns
f_T	transition frequency	$I_C = -50\text{ mA}; V_{CE} = -10\text{ V}; f = 100\text{ MHz}$	150	220	-	MHz
C_c	collector capacitance	$I_E = i_e = 0\text{ A}; V_{CB} = -10\text{ V}; f = 1\text{ MHz}$	-	9	15	pF

[1] Pulse test: $t_p \leq 300\text{ }\mu\text{s}$; $\delta \leq 0.02$.

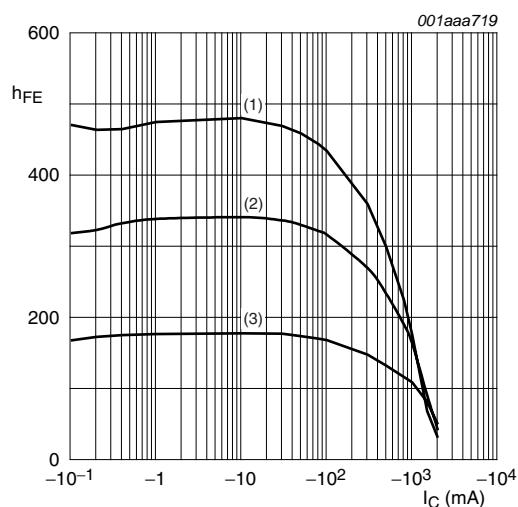


Fig 3. DC current gain as a function of collector current; typical values

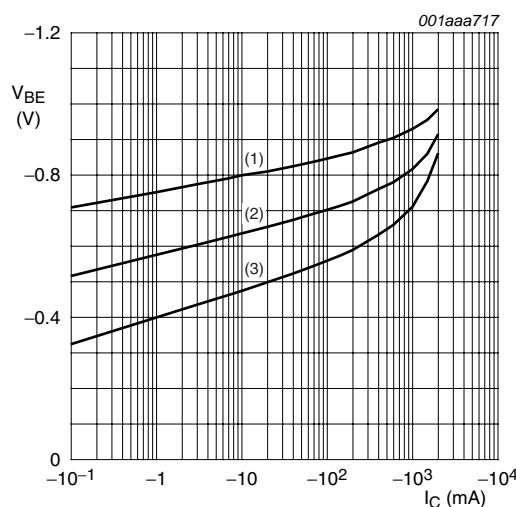


Fig 4. Base-emitter voltage as a function of collector current; typical values

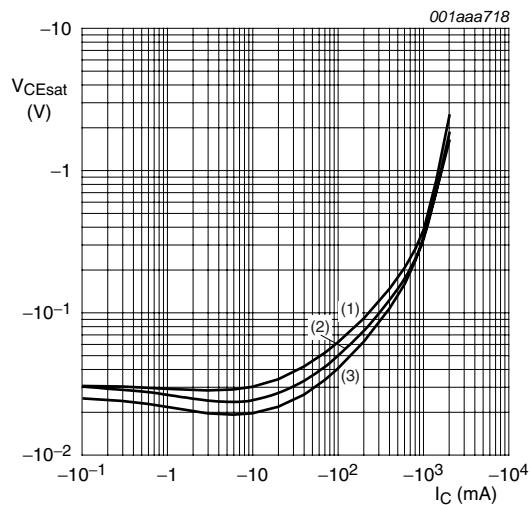


Fig 5. Collector-emitter saturation voltage as a function of collector current; typical values

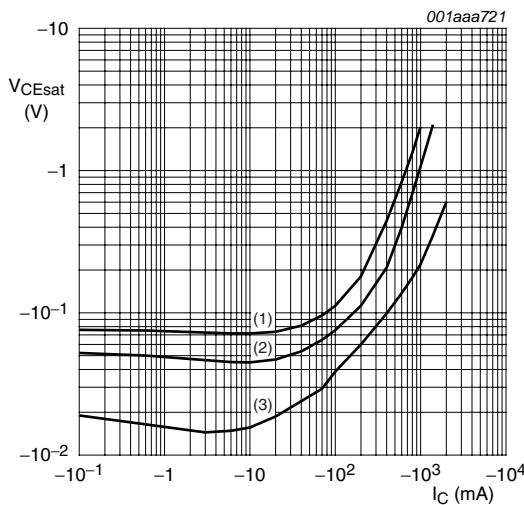


Fig 6. Collector-emitter saturation voltage as a function of collector current; typical values

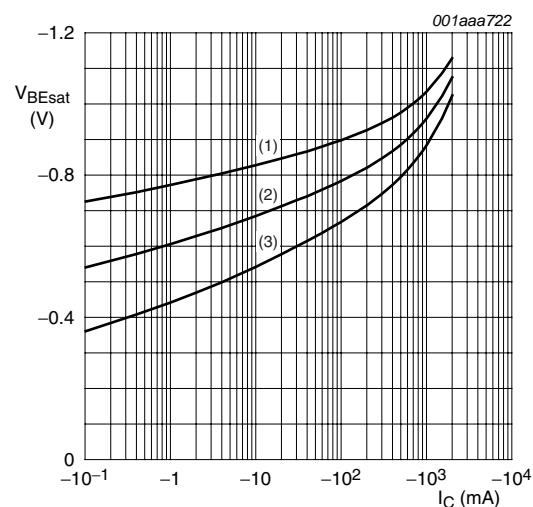


Fig 7. Base-emitter saturation voltage as a function of collector current; typical values

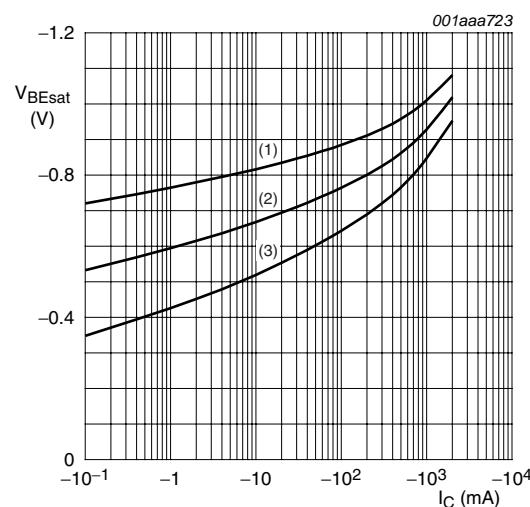
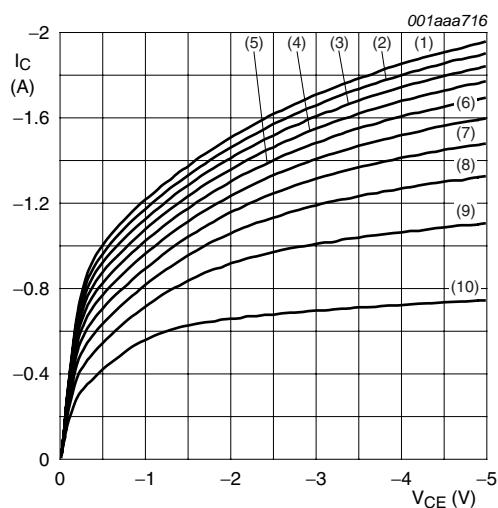


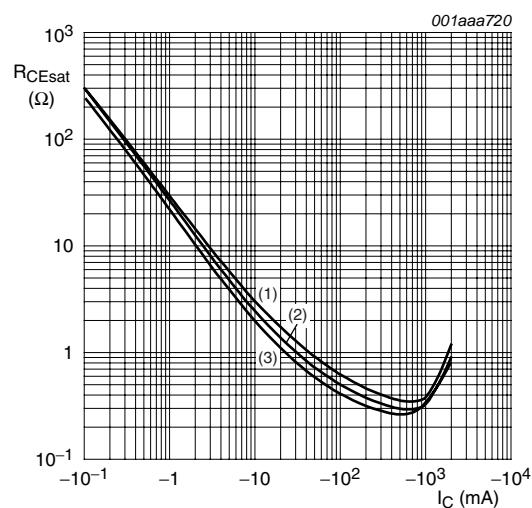
Fig 8. Base-emitter saturation voltage as a function of collector-current; typical values



$T_{amb} = 25^\circ\text{C}$

- (1) $I_B = -40$ mA
- (2) $I_B = -36$ mA
- (3) $I_B = -32$ mA
- (4) $I_B = -28$ mA
- (5) $I_B = -24$ mA
- (6) $I_B = -20$ mA
- (7) $I_B = -16$ mA
- (8) $I_B = -12$ mA
- (9) $I_B = -8$ mA
- (10) $I_B = -4$ mA

Fig 9. Collector current as a function of collector-emitter voltage; typical values



$I_C/I_B = 20$

- (1) $T_{amb} = 100^\circ\text{C}$
- (2) $T_{amb} = 25^\circ\text{C}$
- (3) $T_{amb} = -55^\circ\text{C}$

Fig 10. Equivalent on-resistance as a function of collector current; typical values

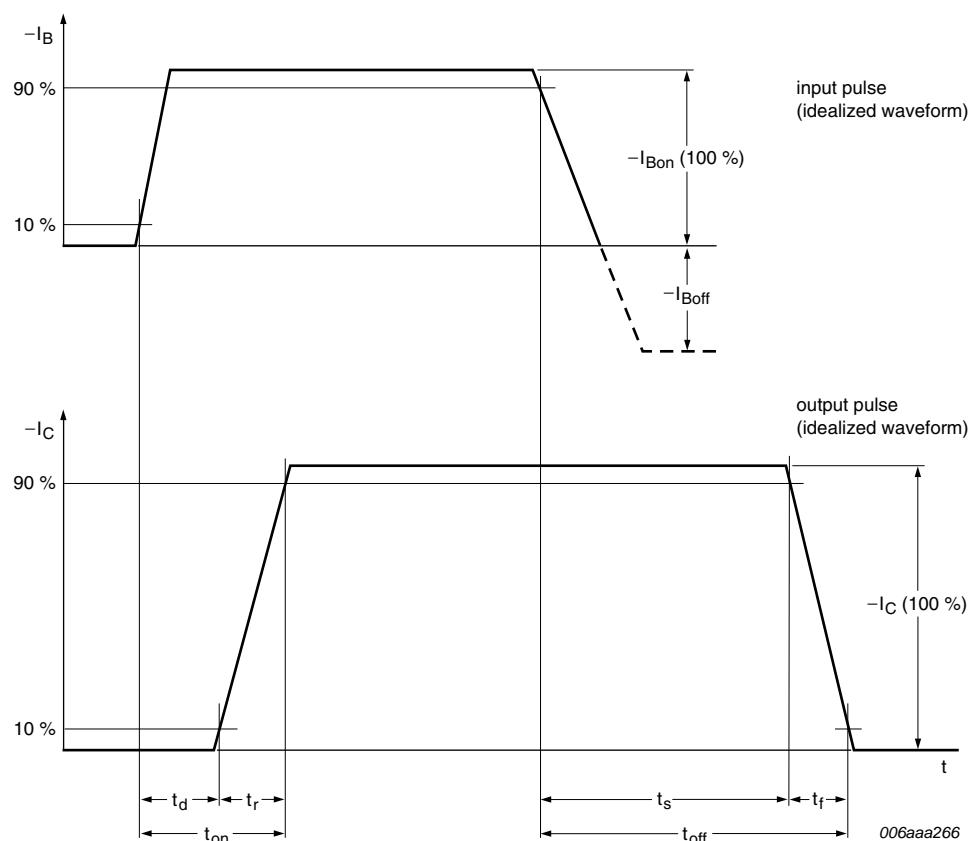
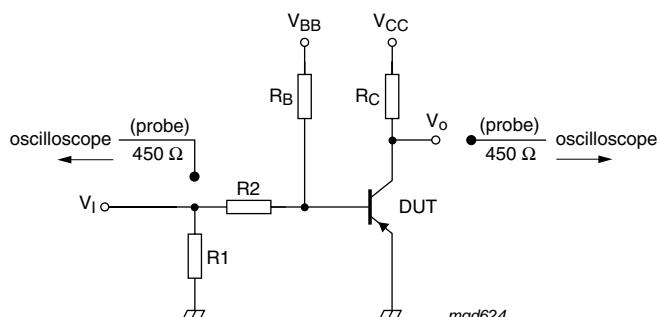


Fig 11. BISS transistor switching time definition



$V_{CC} = -10 \text{ V}$; $I_C = -0.5 \text{ A}$; $I_{Bon} = -0.025 \text{ A}$; $I_{Boff} = 0.025 \text{ A}$

Fig 12. Test circuit for switching times

8. Package outline

Plastic surface-mounted package; 6 leads

SOT666

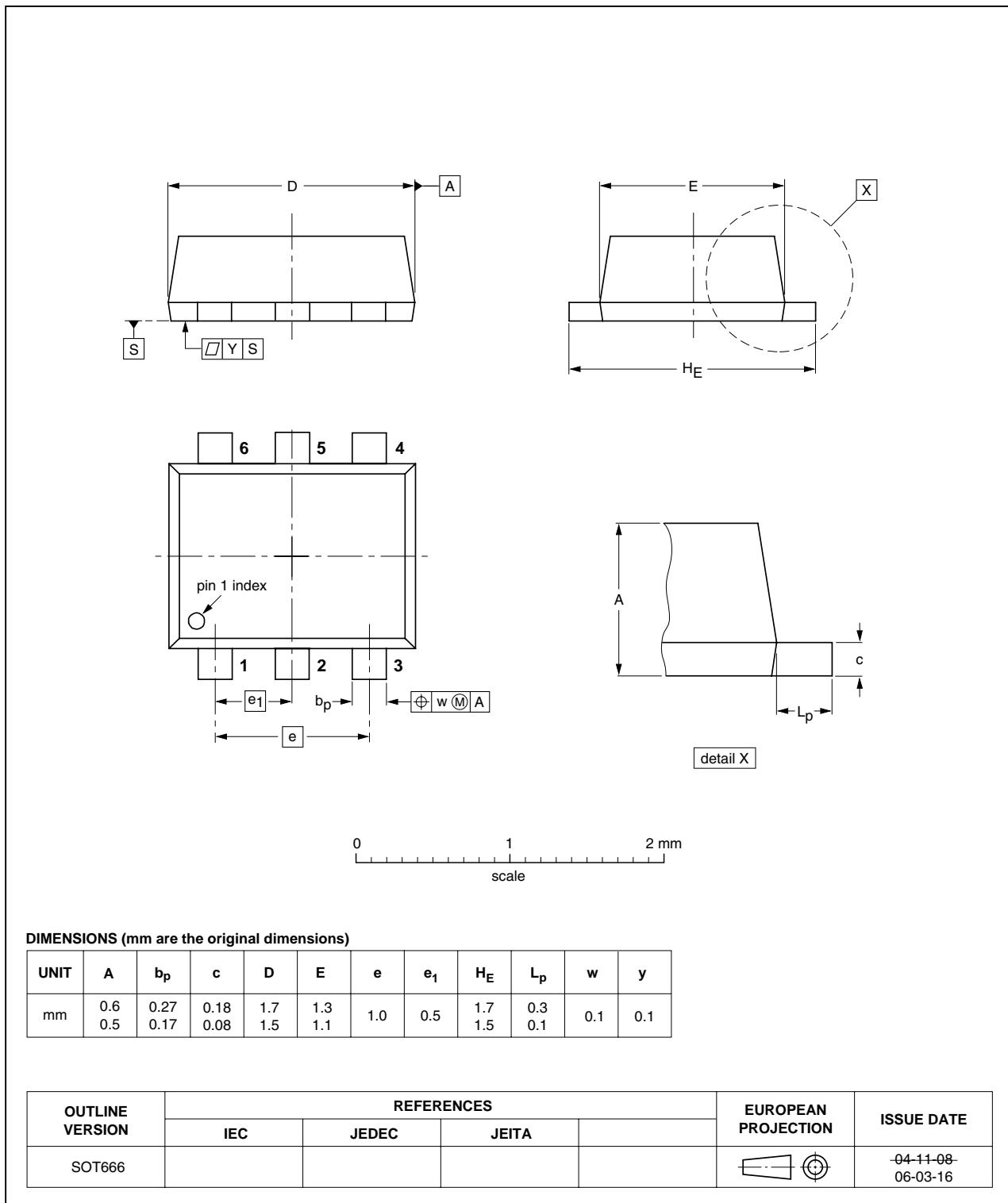


Fig 13. Package outline SOT666

9. Packing information

Table 8. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.^[1]

Type number	Package	Description	Packing quantity
PBSS5160V	SOT666	4 mm pitch, 8 mm tape and reel	3000 -115

[1] For further information and the availability of packing methods, see [Section 12](#).

10. Revision history

Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PBSS5160V_3	20091214	Product data sheet	-	PBSS5160V_2
Modifications:	<ul style="list-style-type: none">This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content.Figure 13 "Package outline SOT666": updated			
PBSS5160V_2	20050404	Product data sheet	-	PBSS5160V_1
PBSS5160V_1	20040420	Objective data sheet	-	-

11. Legal information

11.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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